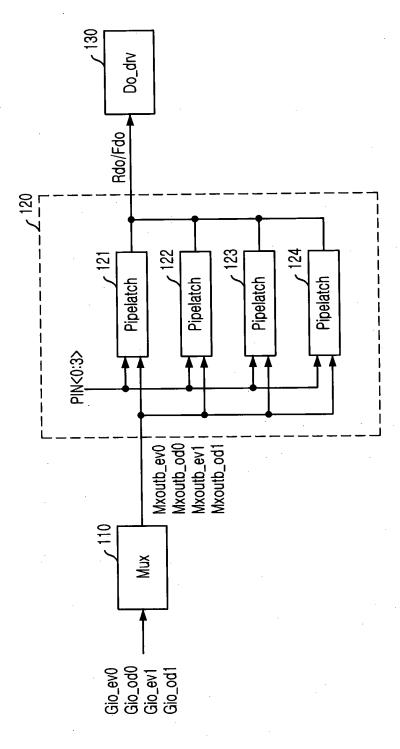
Title: SEMICONDUCTOR MEMORY DEVICE HAVING
ADVANCED PREFETCH BLOCK
1st Named Inventor: Young-Jin YOON
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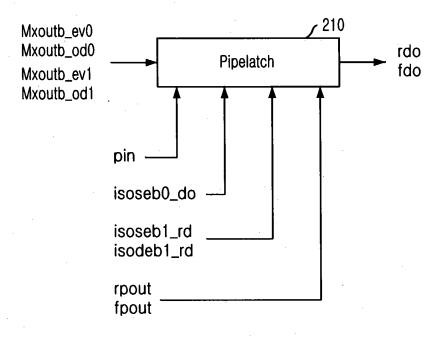
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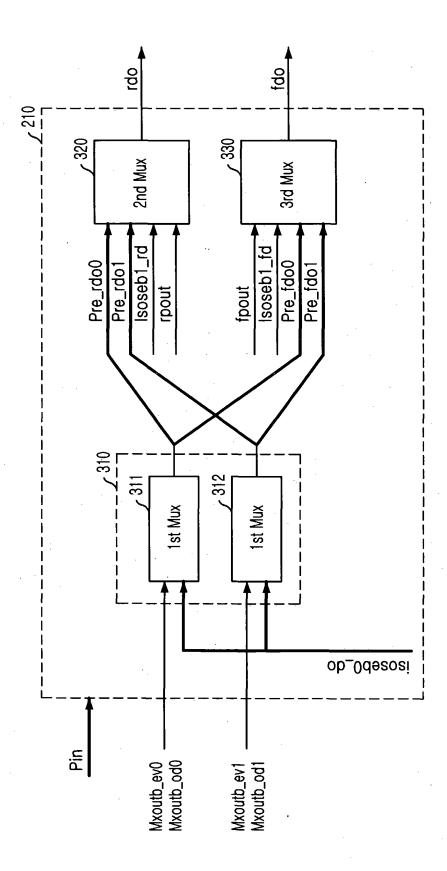
FIG. 2



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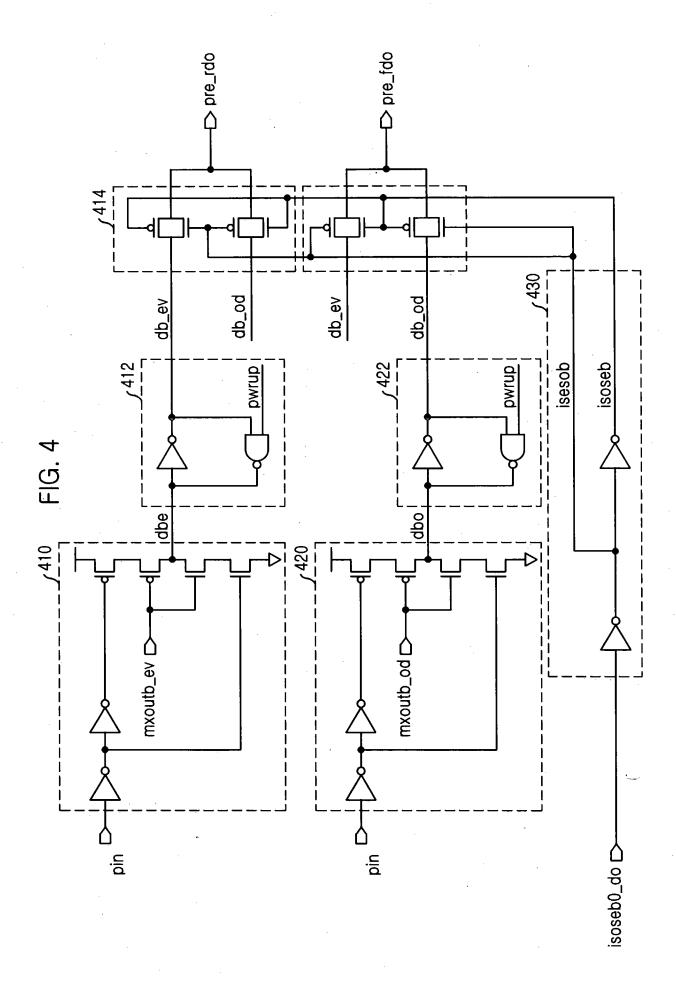
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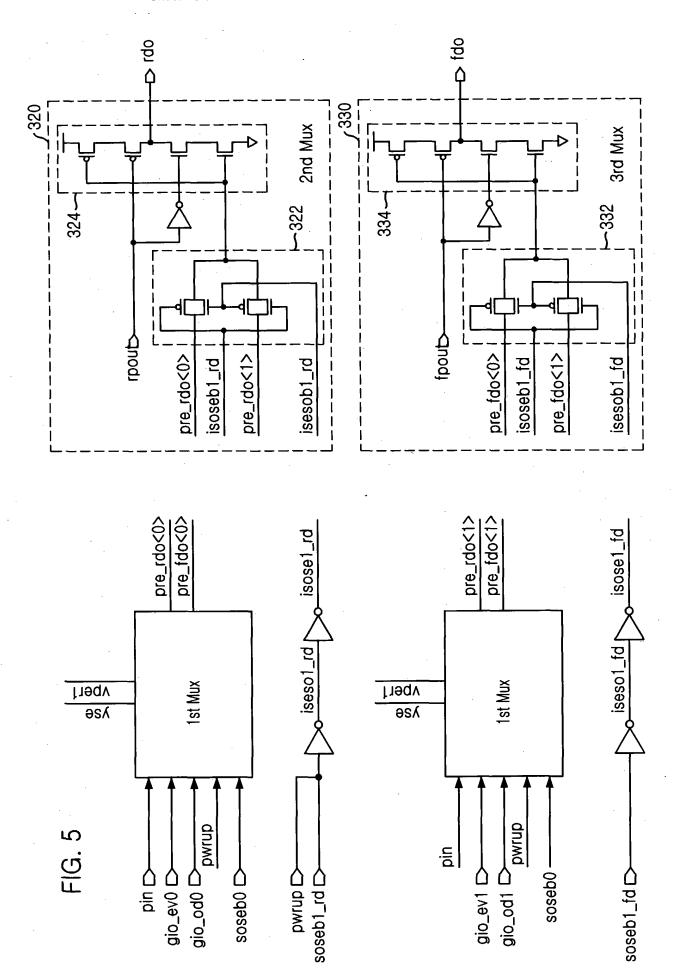
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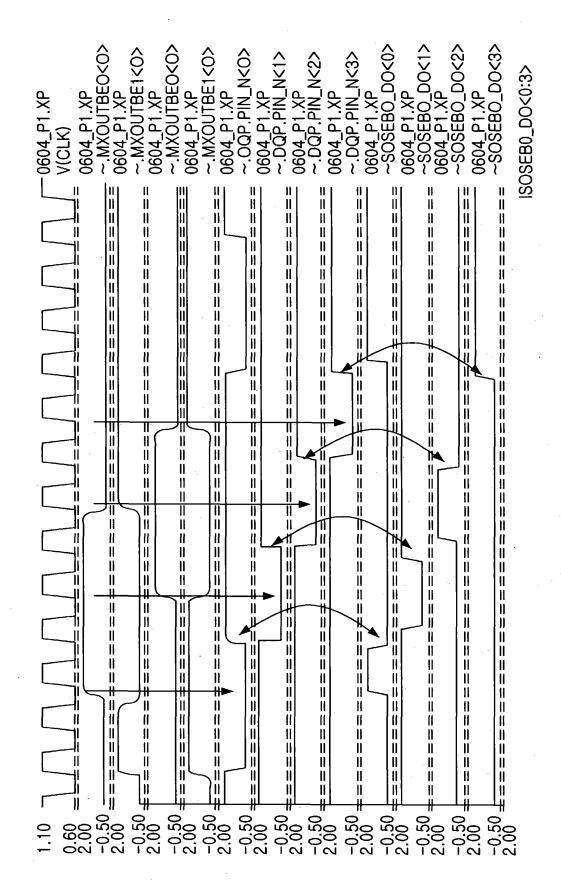
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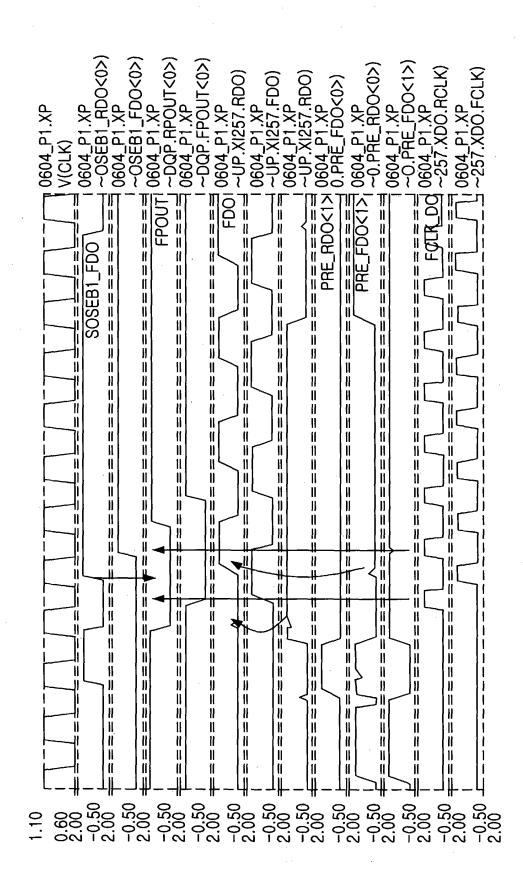
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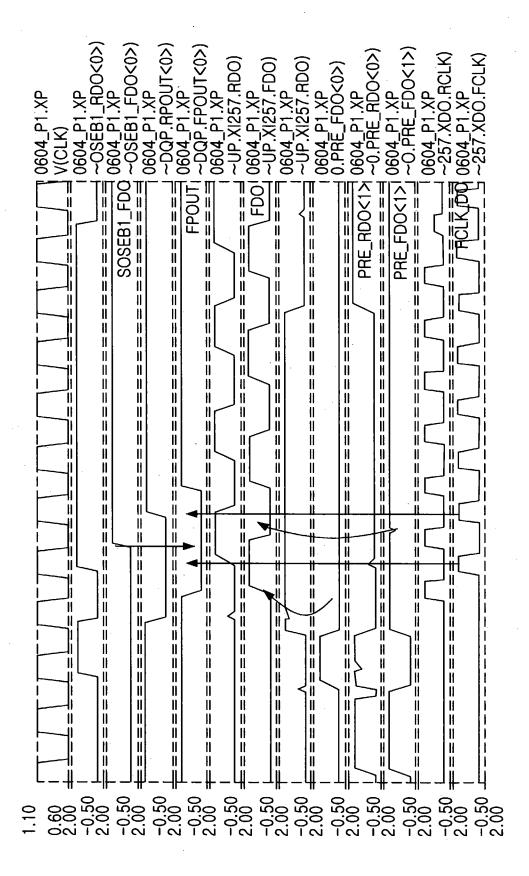


F1G. 7

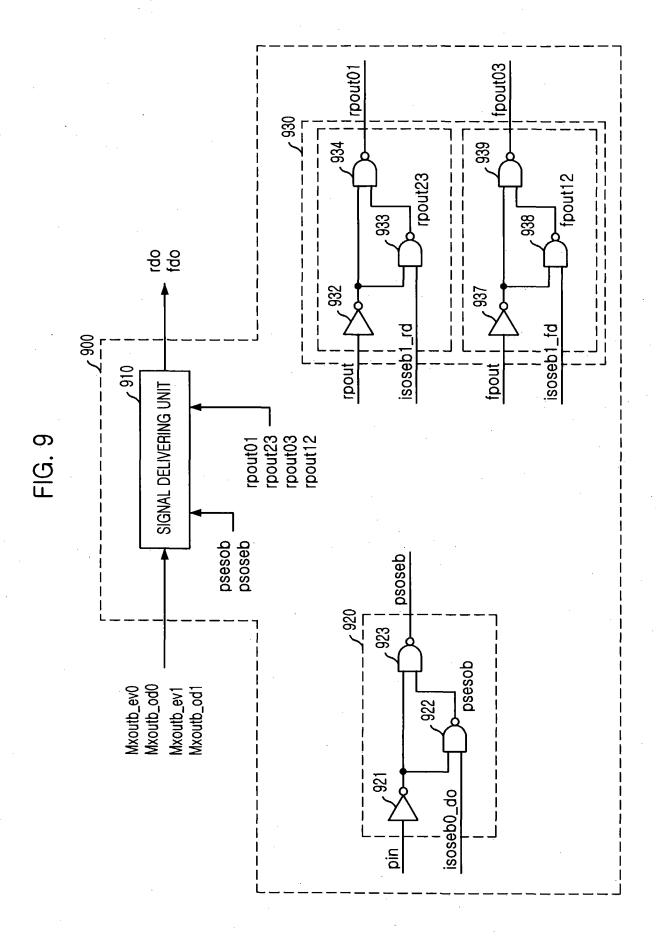
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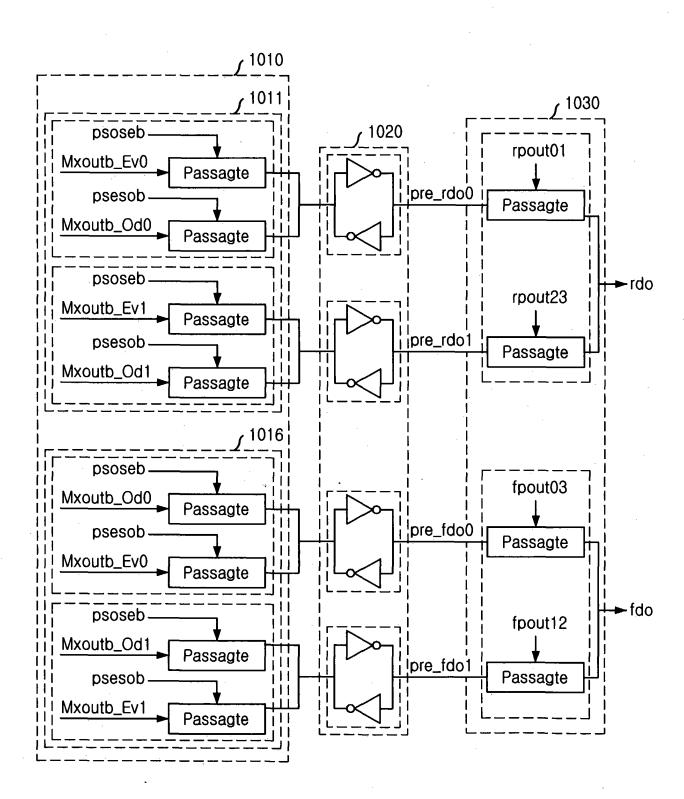
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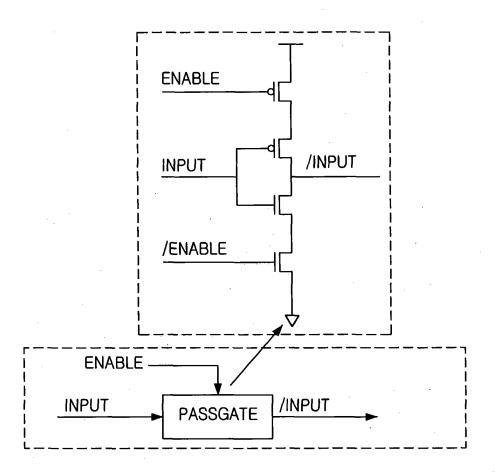
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FIG. 10



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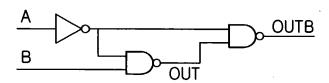
FIG. 11A



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FIG. 11B



	A:"H" B:DON'T CARE	A:"L" B:"H"	A:"L" B:"L"
OUT	HIGH	LOW	HIGH
OUTB	HIGH	HIGH	LOW